

**IN THE CLAIMS**

1-31 (Canceled)

32. (Original) A method for fabricating an infrared optical element from a wafer of material capable of transmitting infrared radiation therethrough, comprising, in the order listed:

masking a surface of the wafer with a pattern defining a cross section of a field of posts;  
etching the wafer surface so as to form the field of posts to a desired depth;  
masking the field of posts with a shape defining a cavity in the surface of the wafer;  
etching the wafer surface including the field of posts so as to form a cavity in the wafer.

33. (Original) The method of claim 32 where the second etching operation is performed such that the tops of the posts lie below the surface of the cavity.

34. (Original) The method of claim 32 where the second etching operation is performed such that tops of the posts are approximately flush with a bottom surface of the cavity.

35. (Original) The method of claim 32 where the second etching operation is performed such that bottoms of the posts lie below a bottom surface of the cavity.

36. (Original) The method of claim 32 where the cross section of the posts varies along their height.

37. (Original) The method of claim 36 where the cross section decreases along the height.

38. (Original) The method of claim 32 where the first etching operation is a reactive ion etch.

39. (Original) The method of claim 38 where the second etching operation is a reactive ion etch.

40. (Original) The method of claim 32 where the height of the posts after the second etching operation is in the approximate range of  $0.5\mu\text{m}$  to  $4\mu\text{m}$ .

41. (Original) The method of claim 32 further comprising applying an antireflection layer to a side of the wafer opposite the cavity.

42. (Original) The method of claim 32 further comprising mounting an infrared detector to the wafer so as to receive incident infrared radiation through the wafer.

43. (Original) The method of claim 42 where the infrared detector is an array of bolometer pixels.

44. (Original) The method of claim 42 further comprising mounting the detector to the wafer.

45. (Original) The method of claim 44 wherein the detector is hermetically sealed to the wafer.

46. (Original) The method of claim 44 further comprising evacuating the cavity.

47. (Original) A method for fabricating an infrared optical device, comprising:  
masking a surface of a wafer of material capable of transmitting infrared radiation therethrough with a pattern defining a field of posts;  
etching the wafer surface so as to form the field of posts to a desired height;  
applying an antireflection element to the other surface of the wafer;  
sealing the wafer to a substrate containing an array of bolometers.

48. (Original) The method of claim 47 further comprising evacuating a space between the wafer and the substrate.

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Title: INFRARED DETECTOR PACKAGED WITH IMPROVED ANTIREFLECTION ELEMENT

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49. (Original) The method of claim 47 where the posts have varying cross section along their height.

50. (Original) The method of claim 47 further comprising:  
performing the above operations for a plurality of infrared optical devices on the same wafer;

dicing the wafer after sealing it to the substrate containing multiple arrays of bolometers;  
thereafter, dicing the wafer and the substrate to separate individual ones of the devices.

**PRELIMINARY AMENDMENT**

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Page 5

**CONCLUSION**

Claims 1-31 are canceled. Claims 32-50 are therefore pending. The Examiner is invited to contact the below-signed attorney with any questions regarding the present Application.

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By \_\_\_\_\_

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